

L5204F

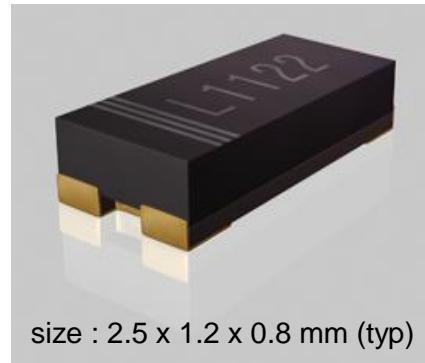
EK0506-0002 Ver.G

PIN Diode



■ FEATURES

- High Power Handling for VHF/UHF band
- Low Capacitance at Zero Bias,
Extremely Small Reverse Bias
- Low Series Resistance
- Very Low Insertion Loss, High Isolation
- RoHS Compliant
- Lead Free / Halogen Free



■ MECHANICAL DATA

- Case : 2512(1005) molded plastic package.
- Terminals : Gold plated, solderable per
MIL-STD-750, method 2026
- Polarity : Indicated by cathode band.

■ DESCRIPTIONS

The L5204F PIN diode is designed for high power antenna switches
in two-way radios.

Suitable for RFID reader and writer application.

■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

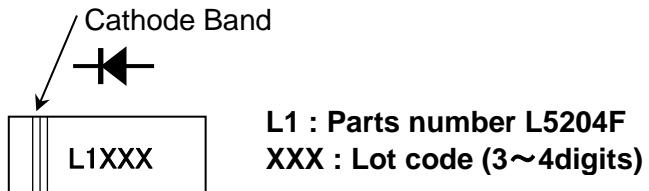
SYMBOL	PARAMETER	RATING	UNITS
V_R	Reverse Voltage	180	V
P_D *	Power Dissipation	500	mW
T_j	Junction Temperature	150	°C
T_{stg}	Storage Temperature Range	-55 to 150	°C

*) Mounting on glass epoxy PCB (50mm x 50mm x 1.6mm)

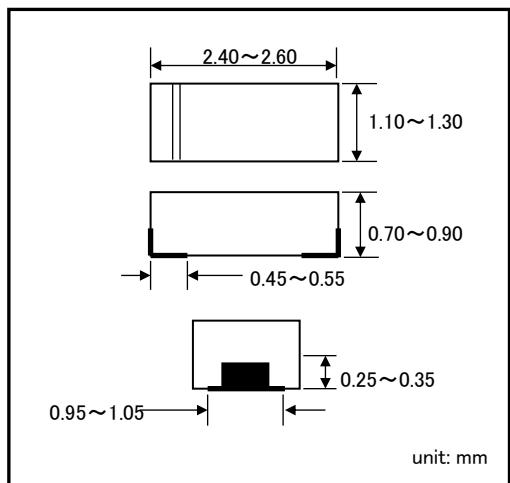
■ ELECTRICAL CHARACTERISTICS (Ta=25°C)

SYMBOL	PARAMETER	CONDITIONS	LIMITS			UNITS
			MIN	TYP	MAX	
I_R	Reverse Current	V_R = 180V	-	-	10	µA
V_F	Forward Voltage	I_F = 100mA	-	-	1.0	V
C_T	Diode Capacitance	V_R =40V, f = 100MHz	-	-	0.9	pF
R_fs	Forward Series Resistance	I_F = 50mA, f = 100MHz	-	0.5	0.75	Ω

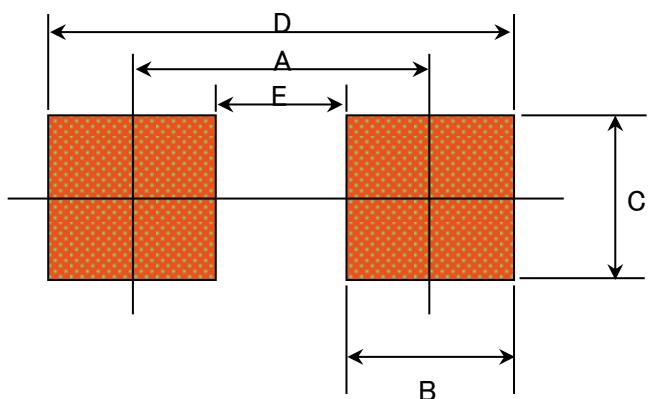
■ MARKING INFORMATION



■ PACKAGE OUTLINE INFORMATION



■ SUGGESTED PAD LAYOUT



Size	2512(1005)
A	2.1
B	1.2
C	1.2
D	3.3
E	0.9
unit	mm

■ TYPICAL PERFORMANCE CHARACTERISTICS

